AOS SEMICONDUCTOR

产品规格说明书

Product Data Sheet

AOS138Xx

电源管理IC　　通信接口芯片　　二三极管　　LDO稳压器　　逻辑器件

MOSFETs　　运算放大器　　显示驱动　　MCU单片机　　光电器件

DESCRIPTIONS

The AOS138, a three to eight decoders/demultiplexers, is designed for 2V to 5.5V $_{cc}$ Voperation.

The AOS138 is consist of three enable inputs (E3,¬ E2 and E1), three binary weighted addressinputs (A0, A1 and A2) and eight outputs(¬ Y0 to ¬ Y7). Among all enable inputs, one is active high output enable (E3) and two are active low output enables (¬ E2 and ¬ E1). When the outputs are gated by any of the strobe inputs, they are all forced into the high state. When the outputs are not disabled by the strobe inputs, only the selected output is low while all others are high.

The AOS138 is available in Green SOP16 and TSSOP16 packages. It operates over an ambient temperature range of -40℃ to +125℃.

FEATURES

Operating Voltage Range: 2V to 5.5V
Low Power Consumption: 160µA (Max)
I/O Port or Memory Selector
Three Enable Inputs to Simplify Cascading
Balanced Propagation Delay and Transition Times
Operating Temperature Range:-40℃ to +125℃
Inputs Accept Voltage to 5.5V
Micro Size Packages: SOP16, TSSOP16

APPLICATIONS

LED Displays
Servers
White Goods
Power Infrastructure
Factory Automation

Device Information [1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
AOS138	SOP16	9.90mm×3.91mm
	TSSOP16	5.00mm×4.40mm

(1)For all available packages, see the orderable addendum at the end of the data sheet.
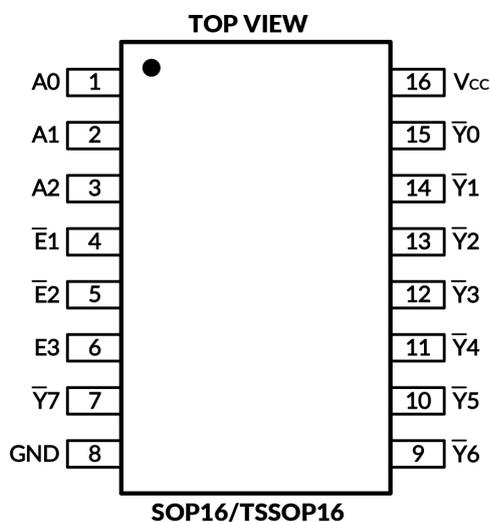
PACKAGE/ORDERING INFORMATION[1]

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING[2]	MSL[3]	PACKAGE OPTION
AOS138	AOS138XTSS16	-40℃~+125℃	TSSOP16	AOS138	MSL3	Tape and Reel,4000
	AOS138XS16-G	-40℃~+125℃	SOP16	AOS138	MSL1	Tape and Reel,4000
	AOS138XTSS16-G	-40℃~+125℃	TSSOP16	AOS138	MSL1	Tape and Reel,4000

NOTE:
(1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser -based versions of this data sheet, refer to the right-hand navigation.
(2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.
(3) MSL,The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications.

PIN CONFIGURATIONS

TOP VIEW

```
        A0 ┌ 1  ●        16 ┐ Vcc
        A1 ┌ 2            15 ┐ Y̅0
        A2 ┌ 3            14 ┐ Y̅1
        E̅1 ┌ 4            13 ┐ Y̅2
        E̅2 ┌ 5            12 ┐ Y̅3
        E3 ┌ 6            11 ┐ Y̅4
        Y̅7 ┌ 7            10 ┐ Y̅5
       GND ┌ 8             9 ┐ Y̅6
```

SOP16/TSSOP16

PIN DESCRIPTION

PIN SOP16/TSSOP16	NAME	I/O TYPE[1]	FUNCTION
1	A0	I	Address input
2	A1	I	Address input
3	A2	I	Address input
4	E1	I	Enable input (active LOW)
5	E2	I	Enable input (active LOW)
6	E3	I	Enable input (active HIGH)
7	Y7	O	Output
8	GND	-	Ground
9	Y6	O	Output
10	Y5	O	Output
11	Y4	O	Output
12	Y3	O	Output
13	Y2	O	Output
14	Y1	O	Output
15	Y0	O	Output
16	Vcc	-	Power Supply

(1)I=input, O=output.

SPECIFICATIONS
Absolute Maximum Ratings
Over operating free-air temperature range (unless otherwise noted)[1][2]

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
I_{IK}	Input clamp diode current	For $V_I< 0.5V$ or $V_I> V_{CC}+0.5V$		±20	mA
I_{OK}	Output clamp diode current	For $V_O< -0.5V$ or $V_O> V_{CC}+0.5V$		±20	mA
I_O	Output source or sink current per output pin	For $V_O> -0.5V$ or $V_O< V_{CC}+0.5V$		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
JA	Package thermal impedance [3]	SOP16		150	℃/W
		TSSOP16		45	
T_J	Junction temperature[4]		-65	150	℃
T_{stg}	Storage temperature		-65	150	℃
	Lead temperature (Soldering 10s) (SOIC -Lead Tips Only) 300℃			300	℃

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD-51.

(4) The maximum power dissipation is a function of $T_{J(MAX)}$, R_{JA}, and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D=(T_{J(MAX)}-T_A)/R_{JA}$. All numbers apply for packages soldered directly onto a PCB.

ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-Body Model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	± 2000	V
		Charged-Device Model (CDM), per ANSI/ESDA/JEDEC JS-002[2]	± 1000	
		Machine Model (MM)	± 200	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply Voltage	V_{CC}		4.5	5.5	V
Input Voltage	V_I		0	V_{CC}	V
Output Voltage	V_O		0	V_{CC}	V
Input Rise and Fall Time	t_t	V_{CC}=2V		1000	ns
		V_{CC}=4.5V		500	
		V_{CC}=5.5V		400	
OperatingTemperature	T_A		-40	125	℃

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Electrical Characteristics

PARAMETER	TEST CONDITIONS(4)	V_{CC}	25℃ MIN[2]	25℃ TYP[3]	25℃ MAX[2]	-40℃ to 85℃ MIN[2]	-40℃ to 85℃ TYP[3]	-40℃ to 85℃ MAX[2]	-40℃ to 125℃ MIN[2]	-40℃ to 125℃ TYP[3]	-40℃ to 125℃ MAX[2]	UNIT
V_{IH}		2	1.5			1.5			1.5			V
		4.5	3.15			3.15			3.15			
		5.5	3.85			3.85			3.85			
V_{IL}		2			0.5			0.5			0.5	V
		4.5			1.35			1.35			1.35	
		5.5			1.65			1.65			1.65	
V_{OH}	I_{OH} = -20μA	2	1.9			1.9			1.9			V
	I_{OH} = -20μA	4.5	4.4			4.4			4.4			
	I_{OH} = -20μA	5.5	5.4			5.4			5.4			
	I_{OH} = -4mA	4.5	3.98			3.84			3.7			
	I_{OH} = -5.2mA	5.5	4.95			4.81			4.67			
V_{OL}	I_{OL}= 20μA	2			0.1			0.1			0.1	V
	I_{OL}= 20μA	4.5			0.1			0.1			0.1	
	I_{OL}= 20μA	5.5			0.1			0.1			0.1	
	I_{OL}= 4mA	4.5			0.26			0.33			0.4	
	I_{OL}= 5.2mA	5.5			0.26			0.33			0.4	
I_I	V_I= V_{CC} or GND	5.5			±0.1			±1			±1	μA
I_{CC}	V_I= V_{CC} or GND	5.5			8			80			160	μA

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.
(2) Limits are 100% production tested at 25℃. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.
(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.
(4) V_I = V_{IH} or V_{IL}, unless otherwise noted.

Switching Characteristics

Input t_t= 6ns.

PARAMETER		TEST CONDITIONS(4)	Vcc	Operating free-air temperature (T$_A$)									UNIT
				25℃			-40℃ to 85℃			-40℃ to 125℃			
				MIN (2)	TYP (3)	MAX (2)	MIN (2)	TYP (3)	MAX (2)	MIN (2)	TYP (3)	MAX (2)	
t_{pd}	Address to Output	CL= 50pF	2			51			54			55	ns
			4.5		11	16			18			19	
			5.5			14			16			17	
	Strobe E1, E2, E3 to Output AOS138	CL= 50pF	2			46			49			50	
			4.5			14			15			16	
			5.5			12			13			14	
t_t	Output Transition Time	CL= 50pF	2			39			41			46	
			4.5			14			16			17	
			5.5			12			13			15	
C_{PD}	Power Dissipation Capacitance(4)	CL= 15pF	5		67								pF
C_i	Input Capacitance					10			10			10	

(1) All unused inputs of the device must be held at V$_{CC}$ or GND to ensure proper device operation.

(2) This parameter is ensured bydesign and/or characterization and is not tested in production.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

(4) C$_{PD}$ is used to determine the dynamic power consumption, per gate.

PARAMETER MEAOSUREMENT INFORMATION

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ⩽ 1 MHz, Z_0= 50 , t_t < 6 ns.
For clock inputs, fmax is measured when the input duty cycle is 50%.
The outputs are measured one at a time with one input transition per measurement.
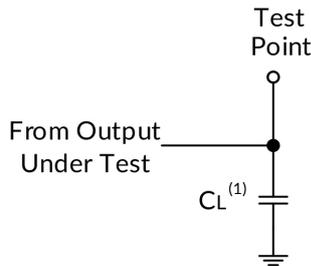
(1) C_L includes probe and test-fixture capacitance.

Figure 1. Load Circuit for Push-Pull Outputs
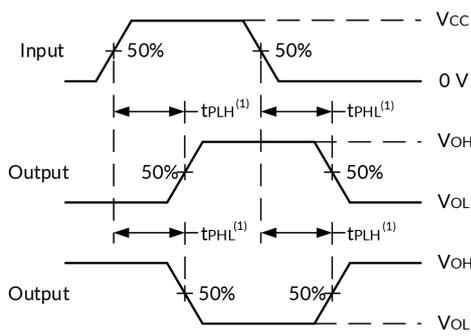
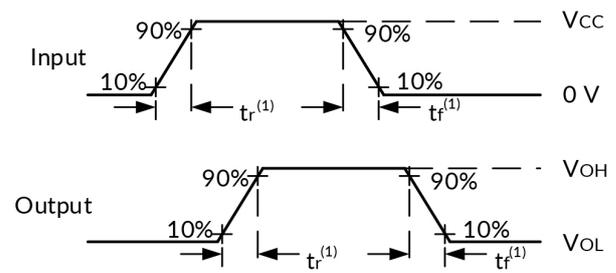(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

(1) The greater between t_{PLH} and t_{PHL} is the same as tpd.

Figure 2. Voltage Waveforms,Propagation Delays for Standard CMOS Inputs

(1) The greater between tr and t_f is the same as t_t.

Figure 3. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs
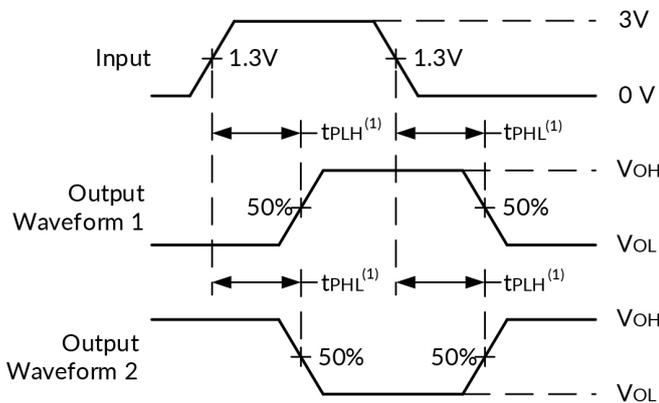
(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

Figure 4. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs

DETAILED DESCRIPTION

Overview

The AOS138 device is 3-to-8 decoders/demultiplexers. The three address input pins, A0, A1, and A2, select which output is active. The selected output is pulled LOW, while the remaining outputs are all HIGH. The conditions at the binary weighted inputs at the three enable inputs select one of eight output lines. The three enable input pins E3, E2 and E1. One active high enable and two active low enable pins are available, and any enable pin can be deactivated to force all outputs high. All three enable pins must be active for the output to be enabled.
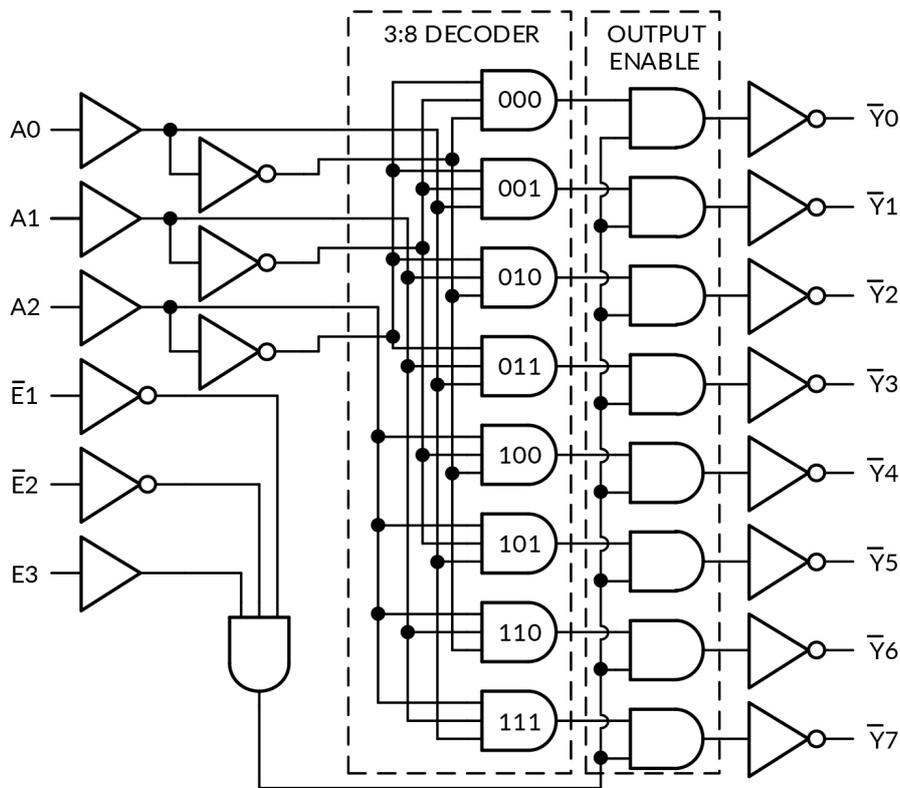
Functional Block Diagram

Figure 5. Functional Block Diagram

Device Functional Modes

Device Function Table

ENABLE INPUTS			ADDRESS INPUTS			OUTPUTS							
E3	E2	E1	A2	A1	A0	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	H	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	L	H	H	H	H	H	L	H	H	H	H
H	L	L	H	L	L	H	H	H	H	L	H	H	H
H	L	L	H	L	H	H	H	H	H	H	L	H	H
H	L	L	H	H	L	H	H	H	H	H	H	L	H
H	L	L	H	H	H	H	H	H	H	H	H	H	L

H: High Voltage Level
L: Low Voltage Level
X: Don't care

POWER SUPPLY RECOMMENDATIONS

The power supply pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1μF capacitor is recommended and if there are multiple V_{cc} terminals then 0.01μF or 0.022μF capacitors are recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies ofnoise.The 0.1μF and 1μF capacitors arecommonly usedin parallel.The bypass capacitor should be installed as close to the power terminal as possible.

LAYOUT

Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally,they will be tied to GND or VCC whichever make more sense or is more convenient.
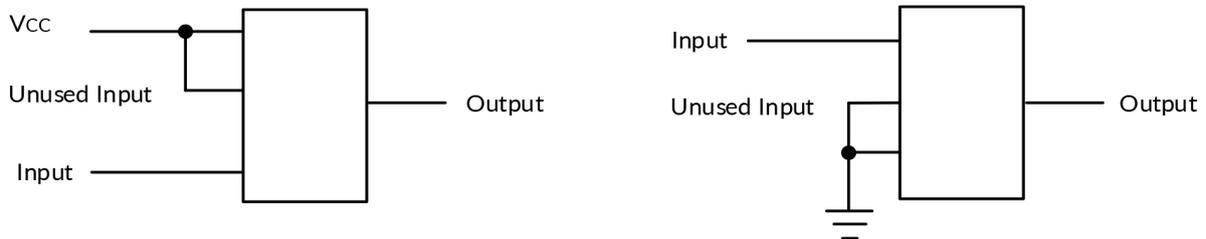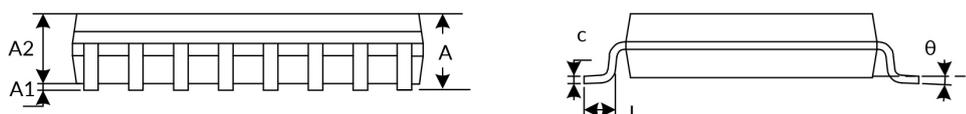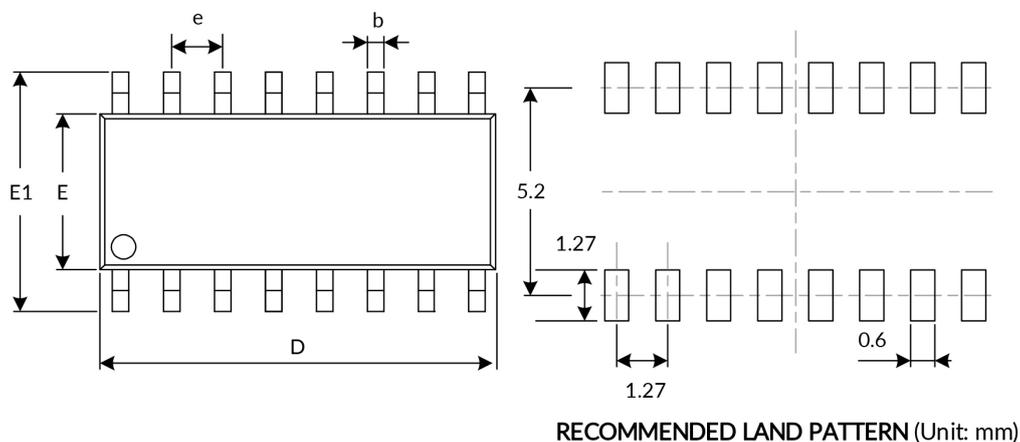
Layout Example

Figure 6. Layout Diagram

PACKAGE OUTLINE DIMENSIONS
SOP16[3]

RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A[1]	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D[1]	9.800	10.200	0.386	0.402
E[1]	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)[2]		0.050(BSC)[2]	
L	0.400	1.270	0.016	0.050
	0°	8°	0°	8°

NOTE:
1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

TSSOP16[3]

RECOMMENDED LAND PATTERN (Unit: mm)
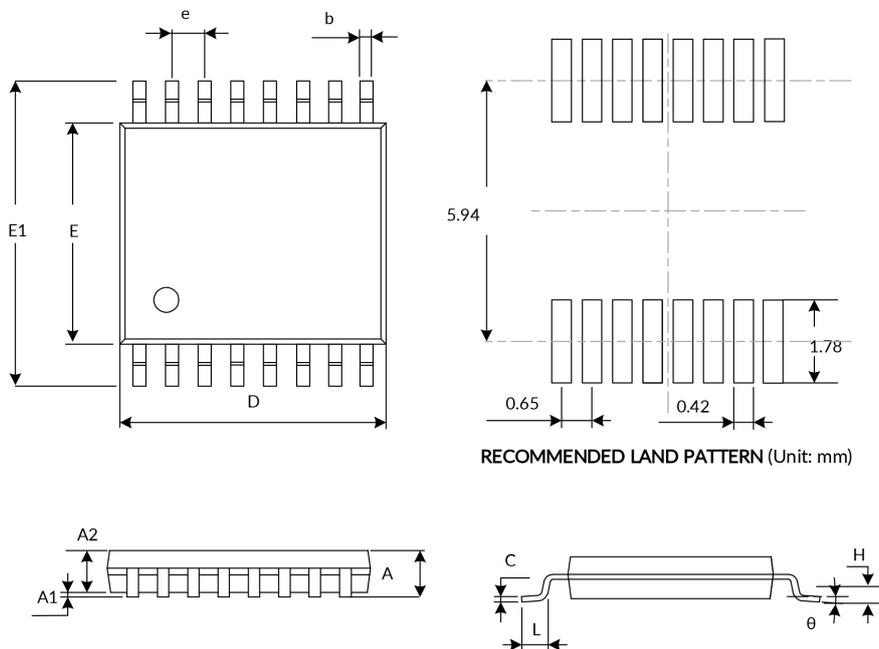
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A[1]		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D[1]	4.860	5.100	0.191	0.201
E[1]	4.300	4.500	0.169	0.177
E1	6.200	6.600	0.244	0.260
e	0.650(BSC)[2]		0.026(BSC)[2]	
L	0.500	0.700	0.02	0.028
H	0.250 TYP		0.010 TYP	
θ	1°	7°	1°	7°

NOTE:
1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

TAPE AND REEL INFORMATION

REEL DIMENSIONS   TAPE DIMENSION
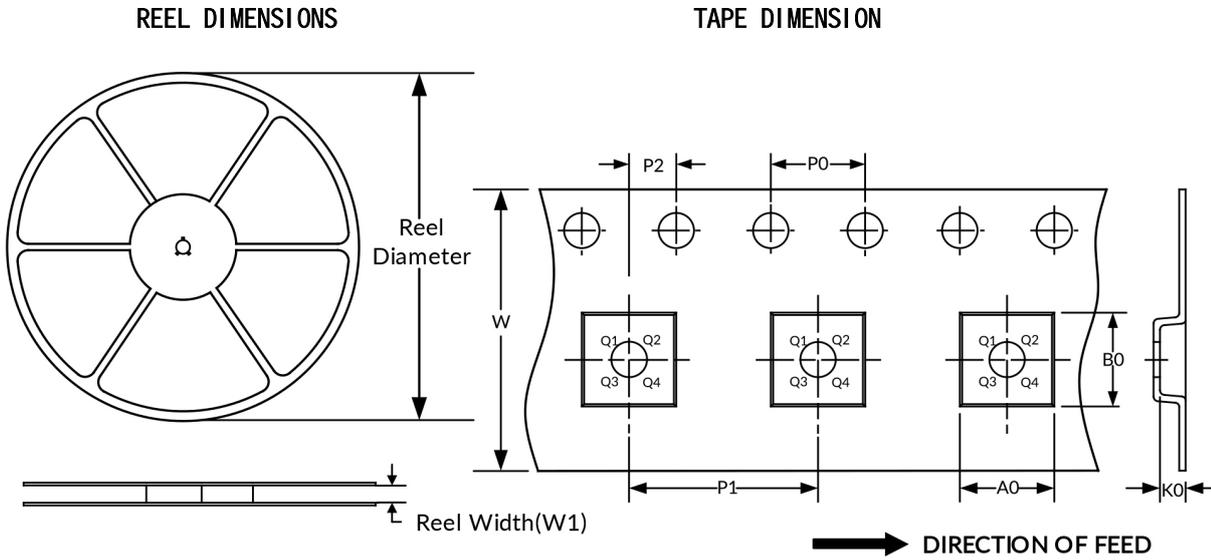
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOP16	13''	16.4	6.50	10.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP16	13''	12.4	6.90	5.60	1.20	4.0	8.0	2.0	12.0	Q1

NOTE:
1. All dimensions are nominal.
2. Plastic or metal protrusions of 0.15mm maximum per side are not included.